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Vishay Siliconix

Automotive N-Channel 100 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	100				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0095				
I _D (A)	120				
Configuration	Single				
Package	TO-263				



FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- AEC-Q101 qualified d
- 100 % R_a and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



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N-Channel MOSFET	O S
N-CHAIRE MOSFET	5

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-Source Voltage		V_{DS}	100	V		
Gate-Source Voltage		V_{GS}	± 20	V		
Continuous Drain Current	T _C = 25 °C ^a	1	120			
Continuous Drain Current	T _C = 125 °C	l _D	73			
Continuous Source Current (Diode Conduction) a		I _S	120	Α		
Pulsed Drain Current ^b		I _{DM}	480			
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	73			
Single Pulse Avalanche Energy	L = 0.1 IIII1	E _{AS}	266	mJ		
Maximum Power Dissipation ^b	T _C = 25 °C	P _D	375	W		
Maximum Fower Dissipation =	T _C = 125 °C	r D	125	VV		
Operating Junction and Storage Temperature Range	T_J , T_{stg}	-55 to +175	°C			

THERMAL RESISTANCE RATINGS							
PARAMETER		SYMBOL	LIMIT	UNIT			
Junction-to-Ambient	PCB Mount c	R_{thJA}	40	°C/W			
Junction-to-Case (Drain)		R_{thJC}	0.4	C/VV			

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. Parametric verification ongoing.



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SPECIFICATIONS (T _C = 25 °C, PARAMETER	SYMBOL		T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static	STWIDOL	120	T CONDITIONS	IVIIIV.	1117.	WAA.	Olaii
Drain-Source Breakdown Voltage			= 0, I _D = 250 μA	100	Ι _		
	V _{DS}		·			-	V
Gate-Source Threshold Voltage	V _{GS(th)}	50	= V _{GS} , I _D = 250 μA	2.5	3.0	3.5	
Gate-Source Leakage	I _{GSS}	20	$0 \text{ V}, \text{V}_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA
		V _{GS} = 0 V	V _{DS} = 100 V	-	-	1	_
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 100 V, T _J = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	$V_{DS} = 100 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$	-	-	150	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	V _{DS} ≥ 5 V	120	-	-	Α
Drain-Source On-State Resistance ^a		V _{GS} = 10 V	I _D = 30 A	-	0.0079	0.0095	
	R _{DS(on)}	$V_{GS} = 10 \text{ V}$	$I_D = 30 \text{ A}, T_J = 125 ^{\circ}\text{C}$	-	-	0.0190	Ω
			$I_D = 30 \text{ A}, T_J = 175 ^{\circ}\text{C}$	-	-	0.0250	
Forward Transconductance b	9 _{fs}	V _{DS} = 15 V, I _D = 30 A		-	99	-	S
Dynamic ^b							
Input Capacitance	C _{iss}			-	6915	8645	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	-	635	795	pF
Reverse Transfer Capacitance	C _{rss}			-	280	350	
Total Gate Charge c	Qg			-	120	180	
Gate-Source Charge c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 50 \text{ V}, I_{D} = 85 \text{ A}$	-	30	-	nC
Gate-Drain Charge c	Q _{gd}			-	28.5	-	1
Gate Resistance	Rq		f = 1 MHz	0.25	0.7	2.3	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	21	32	
Rise Time ^c	t _r	V _{DD} :	$V_{DD} = 50 \text{ V}, R_{L} = 0.6 \Omega$		24	36	- ns
Turn-Off Delay Time c	t _{d(off)}	$I_{D} \cong 85 \text{ A}, V_{GEN} = 10 \text{ V}, R_{g} = 2.5 \Omega$		-	52	78	
Fall Time °	t _f			-	16	24	
Source-Drain Diode Ratings and Chara	acteristics b				<u> </u>	1	
Pulsed Current ^a	I _{SM}			_	l -	480	Α
Forward Voltage	V _{SD}	I _F = 85 A, V _{GS} = 0		_	0.9	1.5	V

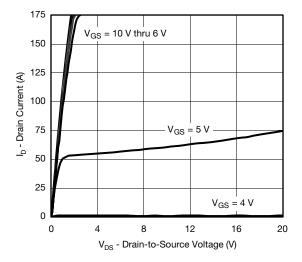
Notes

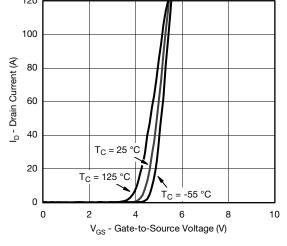
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

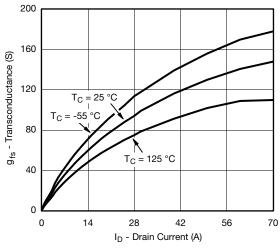


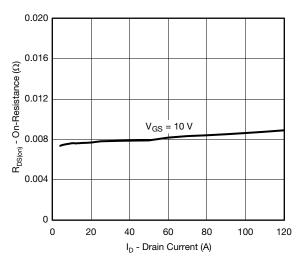


Output Characteristics



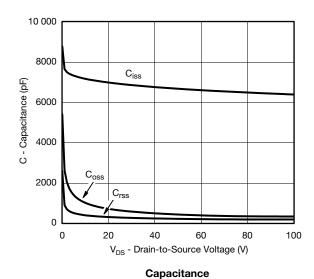


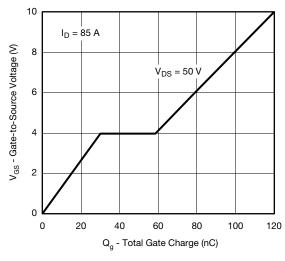




Transconductance

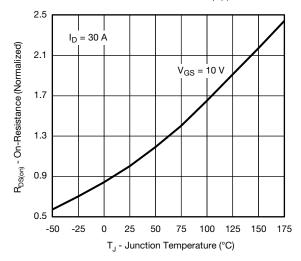
On-Resistance vs. Drain Current



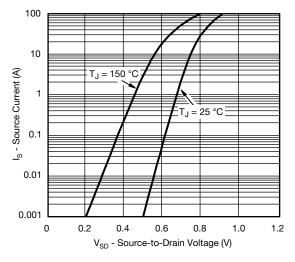




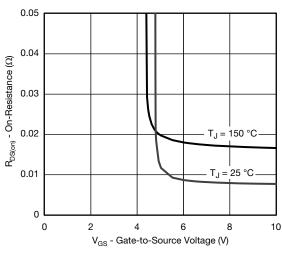
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



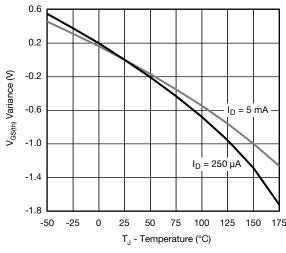
On-Resistance vs. Junction Temperature



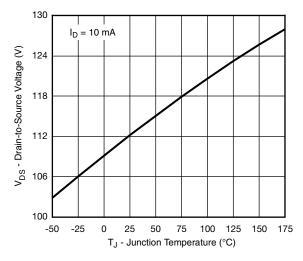
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage

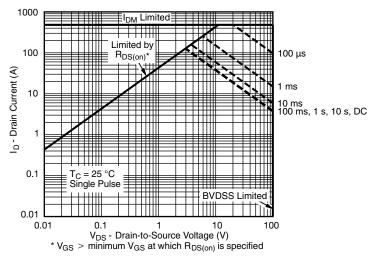


Drain Source Breakdown vs. Junction Temperature

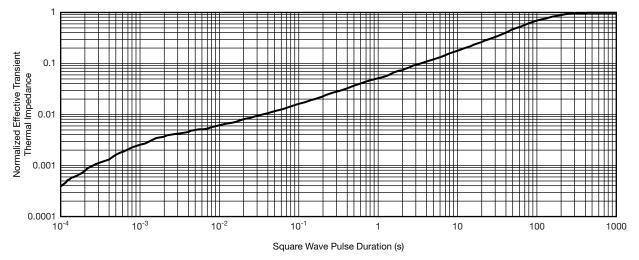
For technical questions, contact: automostechsu



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



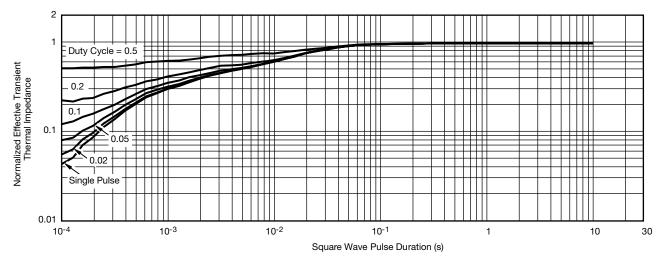
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction to Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg271515.



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REVISION	HISTORY a	
REVISION	DATE	DESCRIPTION OF CHANGE
С	04-Aug-15	Revised R _g minimum limit

Note

a. As of April 2014

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D²PAK / TO-263 and TO-262

Ordering codes for the SQ rugged series power MOSFETs in the D²PAK / TO-263 and TO-262 packages:

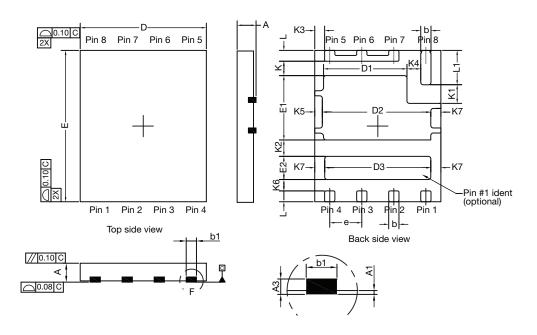
DATASHEET PART NUMBER	OLD ORDERING CODE a	NEW ORDERING CODE
SQM100N04-2m7	SQM100N04-2M7-GE3	SQM100N04-2M7_GE3
SQM100N10-10	SQM100N10-10-GE3	SQM100N10-10_GE3
SQM110N05-06L	SQM110N05-06L-GE3	SQM110N05-06L_GE3
SQM110P06-8m9L	SQM110P06-8M9L-GE3	SQM110P06-8M9L_GE3
SQM120N02-1m3L	SQM120N02-1M3L-GE3	SQM120N02-1M3L_GE3
SQM120N03-1m5L	SQM120N03-1M5L-GE3	SQM120N03-1M5L_GE3
SQM120N04-1m7	SQM120N04-1M7-GE3	SQM120N04-1M7_GE3
SQM120N04-1m7L	SQM120N04-1M7L-GE3	SQM120N04-1M7L_GE3
SQM120N04-1m9	SQM120N04-1M9-GE3	SQM120N04-1M9_GE3
SQM120N06-06	SQM120N06-06-GE3	SQM120N06-06_GE3
SQM120N06-3m5L	SQM120N06-3M5L-GE3	SQM120N06-3M5L_GE3
SQM120N10-09	SQM120N10-09-GE3	SQM120N10-09_GE3
SQM120N10-3m8	SQM120N10-3M8-GE3	SQM120N10-3M8_GE3
SQM120P04-04L	SQM120P04-04L-GE3	SQM120P04-04L_GE3
SQM120P06-07L	SQM120P06-07L-GE3	SQM120P06-07L_GE3
SQM200N04-1m1L	SQM200N04-1M1L-GE3	SQM200N04-1M1L_GE3
SQM200N04-1m7L	SQM200N04-1M7L-GE3	SQM200N04-1M7L_GE3
SQM200N04-1m8	SQM200N04-1M8-GE3	SQM200N04-1M8_GE3
SQM25N15-52	SQM25N15-52-GE3	SQM25N15-52_GE3
SQM35N30-97	SQM35N30-97-GE3	SQM35N30-97_GE3
SQM40N10-30	SQM40N10-30-GE3	SQM40N10-30_GE3
SQM40N15-38	SQM40N15-38-GE3	SQM40N15-38_GE3
SQM40P10-40L	SQM40P10-40L-GE3	SQM40P10-40L_GE3
SQM47N10-24L	SQM47N10-24L-GE3	SQM47N10-24L_GE3
SQM50020EL	-	SQM50020EL_GE3
SQM50N04-4m0L	SQM50N04-4M0L-GE3	SQM50N04-4M0L_GE3
SQM50N04-4m1	SQM50N04-4M1-GE3	SQM50N04-4M1_GE3
SQM50P03-07	SQM50P03-07-GE3	SQM50P03-07_GE3
SQM50P04-09L	SQM50P04-09L-GE3	SQM50P04-09L_GE3
SQM50P06-15L	SQM50P06-15L-GE3	SQM50P06-15L_GE3
SQM50P08-25L	SQM50P08-25L-GE3	SQM50P08-25L_GE3
SQM60N06-15	SQM60N06-15-GE3	SQM60N06-15_GE3
SQM60N20-35	SQM60N20-35-GE3	SQM60N20-35_GE3
SQM85N15-19	SQM85N15-19-GE3	SQM85N15-19_GE3
SQV120N10-3m8	SQV120N10-3m8-GE3	SQV120N10-3m8_GE3
SQV120N06-4m7L	-	SQV120N06-4m7L_GE3

Note

a. Old ordering code is obsolete and no longer valid for new orders



Flip PowerPAIR® 6 x 5 BWL Case Outline



DIMENSION		MILLIMETERS			INCHES	
DIMENSION	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
Α	0.70	0.75	0.80	0.028	0.030	0.032
A1	0.00	=	0.10	0.000	-	0.004
A3	0.15	0.20	0.25	0.006	0.008	0.010
b	0.35	0.41	0.46	0.014	0.016	0.018
b1		0.41 BSC			0.016 BSC	
D	4.90	5.00	5.10	0.193	0.197	0.201
D1	3.26	3.31	3.36	0.128	0.130	0.132
D2	4.20	4.25	4.30	0.165	0.167	0.169
D3	4.15	4.20	4.25	0.163	0.165	0.167
Е	5.90	6.00	6.10	0.232	0.236	0.240
E1	2.50	2.55	2.60	0.098	0.100	0.102
E2	0.87	0.92	0.97	0.034	0.036	0.038
е		1.27 BSC			0.050 BSC	
K		0.57 typ.			0.022 typ.	
K1	0.69	0.74	0.79	0.027	0.029	0.031
K2	0.60	0.65	0.70	0.024	0.026	0.028
K3		0.39 BSC			0.015 BSC	
K4	0.50	0.55	0.60	0.020	0.022	0.024
K5	0.25	0.30	0.35	0.010	0.012	0.014
L	0.33	0.43	0.53	0.013	0.017	0.021
L1	1.31	1.36	1.41	0.052	0.054	0.056
ECN: T15-0457-Rev. A, 17-Aug-15 DWG: 6043						

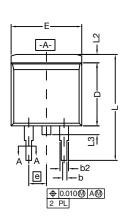
Note

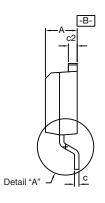
• Millimeters will govern.

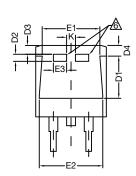
Revision: 17-Aug-15 1 Document Number: 67777



TO-263 (D²PAK): 3-LEAD

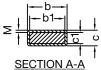








DETAIL A (ROTATED 90°)



_	,	—b - -b	 			1
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- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6 This feature is for thick lead.

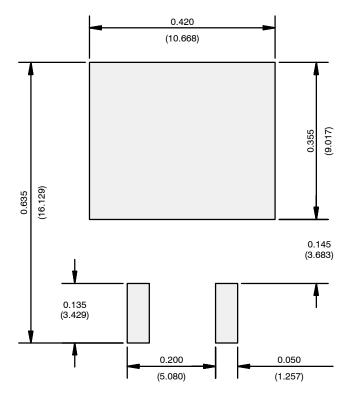
		INC	HES	MILLIMETERS		
	DIM.	MIN.	MAX.	MIN.	MAX.	
	Α	0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
c*	Thin lead	0.013	0.018	0.330	0.457	
C	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
	D3	0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	Е	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	=	
	E2	0.355	0.375	9.017	9.525	
	E3	0.072	0.078	1.829	1.981	
	е	0.100) BSC	2.54	BSC	
	K	0.045	0.055	1.143	1.397	
	L	0.575	0.625	14.605	15.875	
	L1	0.090	0.110	2.286	2.794	
	L2	0.040	0.055	1.016	1.397	
	L3	0.050	0.070	1.270	1.778	
	L4	0.010	0.010 BSC		BSC	
	М	-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13						

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



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Revision: 02-Oct-12 Document Number: 91000

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TPCC8103,L1Q(CM MIC4420CM-TR VN1206L 614234A 715780A NTNS3166NZT5G SSM6J414TU,LF(T 751625C

IPS70R2K0CEAKMA1 BUK954R8-60E DMN3404LQ-7 NTE6400 SQJ402EP-T1-GE3 2SK2614(TE16L1,Q) 2N7002KW-FAI

DMN1017UCP3-7 EFC2J004NUZTDG ECH8691-TL-W FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7 NTE221 NTE2384

NTE2903 NTE2941 NTE2945 NTE2946 NTE2960 NTE2967 NTE2969 NTE2976 NTE455 NTE6400A NTE2910 NTE2916 NTE2956

NTE2911 US6M2GTR TK10A80W,S4X(S SSM6P69NU,LF